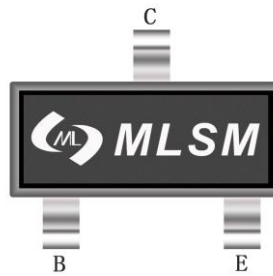


**Features**

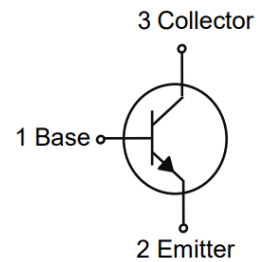
- Low Noise and High Gain
- High Power Gain

**Application**

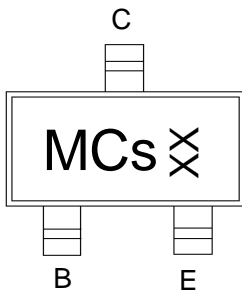
- low noise amplifier at VHF, UHF and CATV band applications



SOT-23 top view



Schematic diagram



MCs= Device code

XX= Code

Marking and pin assignment



Pb-Free



RoHS



Halogen-Free

**Maximum Ratings(Ta=25°C unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	25	V
$V_{CEO}$	Collector-Emitter Voltage	15	V
$V_{EBO}$	Emitter-Base Voltage	2.5	V
$I_C$	Collector Current	25	mA
$P_C$	Collector Power Dissipation	0.28	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	446	°C/W
$T_J, T_{stg}$	Operation Junction and Storage Temperature Range	-50~+150	°C

**Ordering Information (Example)**

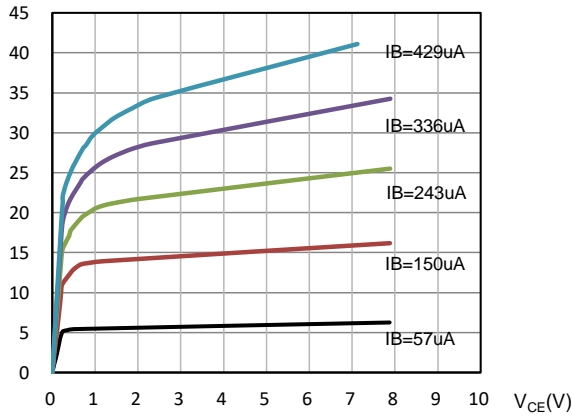
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
BFS17P	SOT-23	MCs	3,000	45,000	180,000	7"reel

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	25	--	--	V
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =1mA, I <sub>B</sub> =0	15	--	--	V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	2.5	--	--	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =10 V, I <sub>E</sub> =0	--	--	0.05	μA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 2.5V, I <sub>C</sub> =0	--	--	100	μA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> =1V, I <sub>C</sub> = 2mA	40	--	150	
		V <sub>CE</sub> =1V, I <sub>C</sub> = 25mA	20	70	--	V
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =10 mA, I <sub>B</sub> = 1mA	--	0.1	0.4	V
C <sub>CB</sub>	Collector Base Capacitance	V <sub>CB</sub> =5V, V <sub>BE</sub> =0V, f=1MHz, Emitter Grounded	--	0.55	--	pF
C <sub>CE</sub>	Collector Emitter Capacitance	V <sub>CE</sub> =5V, V <sub>BE</sub> =0V, f=1MHz, Base Grounded	--	0.27	--	pF
C <sub>EB</sub>	Emitter Base Capacitance	V <sub>EB</sub> =0.5V, V <sub>CB</sub> =0V, f=1MHz, Collector Grounded	--	0.9	--	pF
f <sub>T</sub>	Transition frequency	V <sub>CB</sub> =5V, I <sub>C</sub> =2mA, f=200MHz	1	1.4	--	GHz
		V <sub>CB</sub> =5V, I <sub>C</sub> =25mA, f=200MHz	1.3	2.5	--	GHz

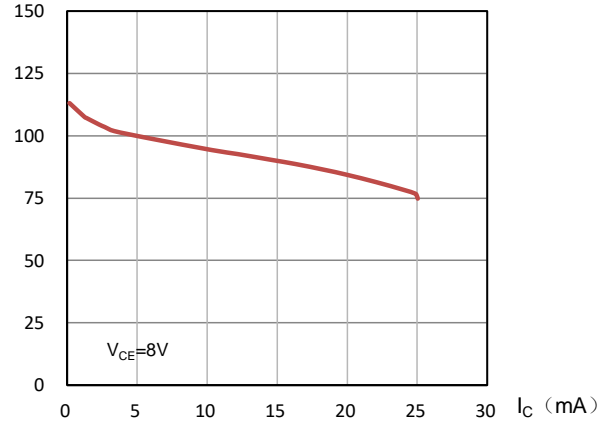
**Typical Operating Characteristics**

$I_C$  (mA)



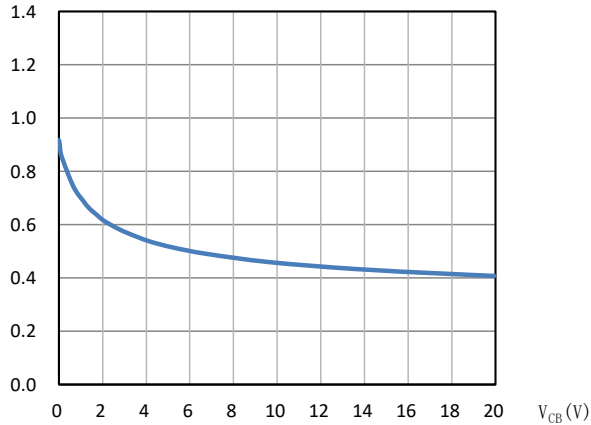
Collector current as a function of collector-emitter voltage; typical values

$h_{FE}$



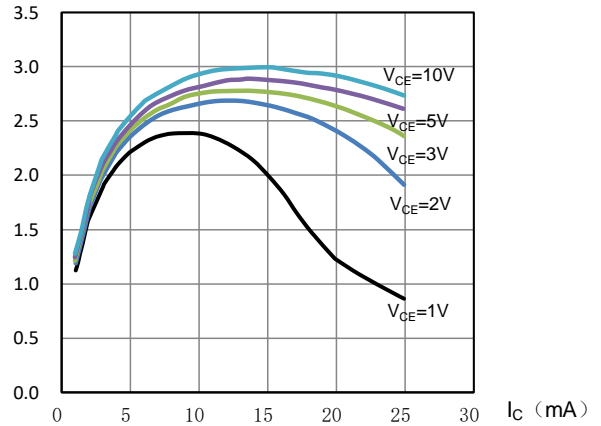
DC current gain as a function of collector current; typical values

$C_{CB}$  (pF)



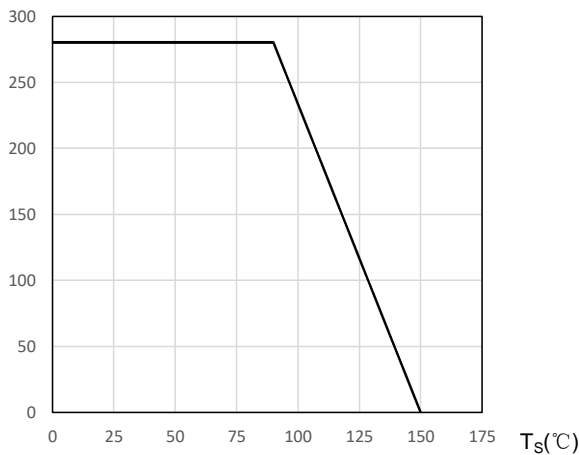
Collector-Base  $C_{CB}=f(V_{CB})$

$f_T$ (GHz)

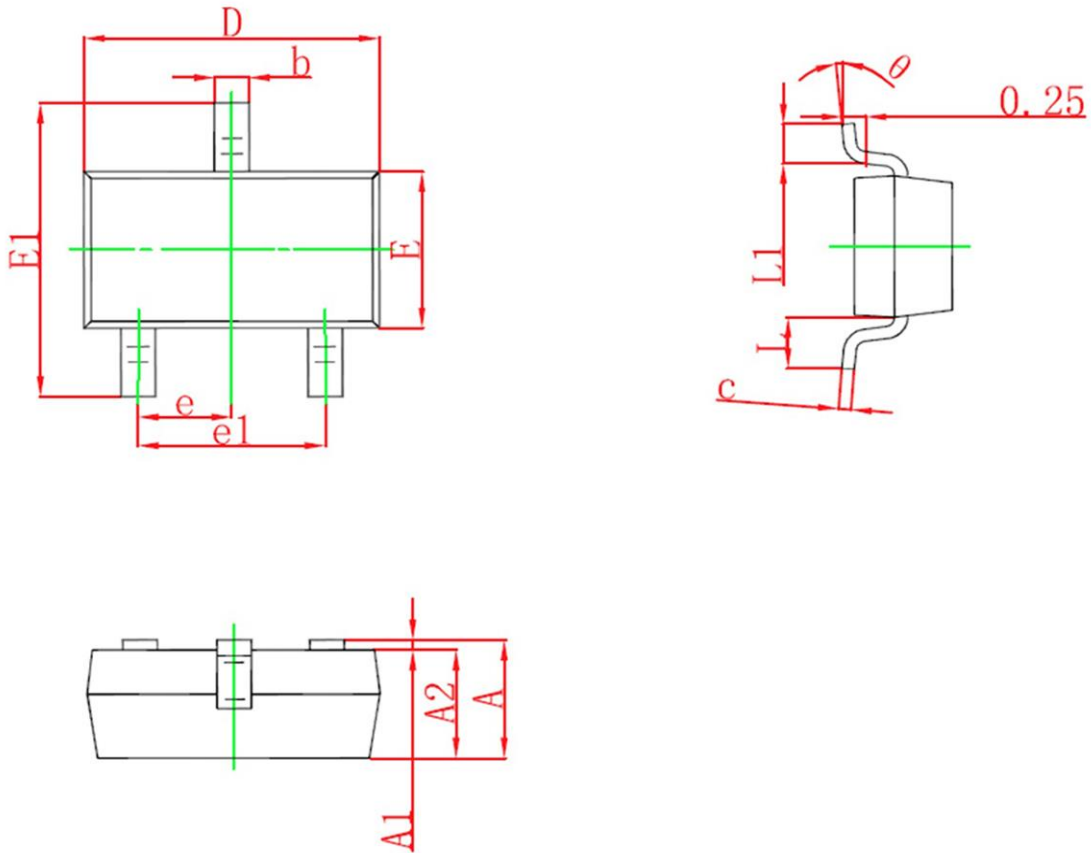


Transition frequency  $f_T = f(I_C)$ ,  
 $V_{CE} = \text{parameter}$

$P_{tot}$ (mW)



Power derating curve

**SOT-23 Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	8°